

# Rectifier diodes schottky barrier

## PBYR1645X series

### GENERAL DESCRIPTION

Low leakage, platinum barrier, schottky rectifier diodes in a full pack plastic envelope, featuring low forward voltage drop, absence of stored charge, and guaranteed reverse surge capability. The devices are intended for use in switched mode power supplies and high frequency circuits in general where low conduction and zero switching losses are important.

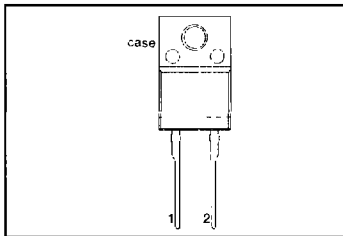
### QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
$V_{RRM}$	Repetitive peak reverse voltage	<b>PBYR16-</b> 35	<b>40X</b> 40	<b>45X</b> 45	V
		$V_F$	0.6	0.6	0.6
$I_{F(AV)}$	Average forward current	20	20	20	A

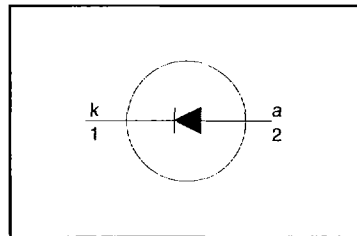
### PINNING - SOD113

PIN	DESCRIPTION
1	cathode
2	anode
case	isolated

### PIN CONFIGURATION



### SYMBOL



### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.			UNIT
				-35	-40	-45	
$V_{RRM}$	Repetitive peak reverse voltage	$T_{hs} \leq 122\text{ }^\circ\text{C}$	-	35	40	45	V
$V_{RWM}$	Crest working reverse voltage		-	35	40	45	V
$V_R$	Continuous reverse voltage		-	35	40	45	V
$I_{F(AV)}$	Average forward current	square wave; $\delta = 0.5$ ; $T_{hs} \leq 110\text{ }^\circ\text{C}$	-	14			A
$I_{F(RMS)}$	RMS output current	$t = 25\text{ }\mu\text{s}$ ; $\delta = 0.5$ ; $T_{hs} \leq 110\text{ }^\circ\text{C}$	-	20			A
$I_{FRM}$	Repetitive peak forward current		-	28			A
$I_{FSM}$	Non-repetitive peak forward current		$t = 10\text{ ms}$ $t = 8.3\text{ ms}$ sinusoidal $T_j = 125\text{ }^\circ\text{C}$ prior to surge; with reapplied	-	120		
			-	132			A
$I^2t$	$I^2t$ for fusing	$V_{RRM(max)}$ $t = 10\text{ ms}$	-	72			$\text{A}^2\text{s}$
$I_{RRM}$	Repetitive peak reverse current	$t_p = 2\text{ }\mu\text{s}$ ; $\delta = 0.001$	-	1			A
$I_{RSM}$	Non-repetitive peak reverse current	$t_p = 100\text{ }\mu\text{s}$	-	1			A
$T_{sig}$	Storage temperature		-65	175			$^\circ\text{C}$
$T_j$	Operating junction temperature		-	150			$^\circ\text{C}$

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**ISOLATION LIMITING VALUE & CHARACTERISTIC**
 $T_{hs} = 25\text{ }^{\circ}\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{isol}$	R.M.S. isolation voltage from all three terminals to external heatsink	$f = 50\text{-}60\text{ Hz}$ ; sinusoidal waveform; $R.H. \leq 65\%$ ; clean and dustfree	-		2500	V
$C_{isol}$	Capacitance from T2 to external heatsink	$f = 1\text{ MHz}$	-	10	-	pF

**THERMAL RESISTANCES**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j\text{-}hs}$	Thermal resistance junction to heatsink	with heatsink compound	-	-	4.2	K/W
$R_{th\ j\text{-}a}$	Thermal resistance junction to ambient	in free air.	-	55	-	K/W

**STATIC CHARACTERISTICS**
 $T_j = 25\text{ }^{\circ}\text{C}$  unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_F$	Forward voltage	$I_F = 16\text{ A}$ ; $T_j = 125\text{ }^{\circ}\text{C}$	-	0.53	0.60	V
		$I_F = 16\text{ A}$	-	0.63	0.68	V
$I_R$	Reverse current	$V_R = V_{RRM}$	-	100	200	$\mu\text{A}$
		$V_R = V_{RRM}$ ; $T_j = 125\text{ }^{\circ}\text{C}$	-	12	40	mA
$C_d$	Junction capacitance	$f = 1\text{ MHz}$ ; $V_R = 5\text{ V}$ ; $T_j = 25\text{ }^{\circ}\text{C}$ to $125\text{ }^{\circ}\text{C}$	-	800	-	pF

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